

## SBD40100TCTB、SBDF40100TCTB

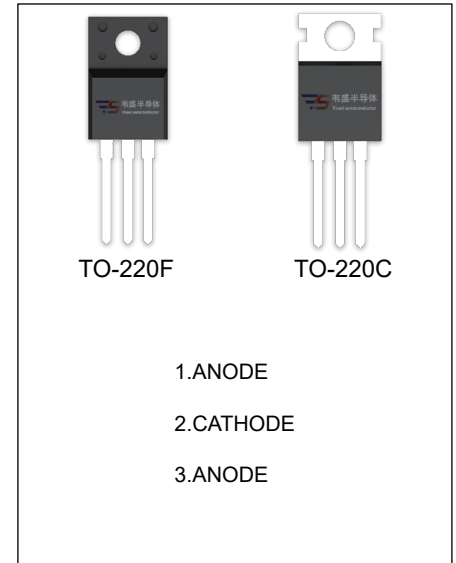
### SCHOTTKY BARRIER RECTIFIER

#### MAIN CHARACTERISTICS

$I_O$	40 (2×20) A
$V_{RRM}$	100 V
$T_j$	150 °C
$V_{F(typ)}$	0.64V (@ $T_j=125^{\circ}C$ )

#### FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



#### MAXIMUM RATINGS ( $T_a=25^{\circ}C$ unless otherwise noted )

Symbol	Parameter	SBD		Unit
		40100TCTB	F40100TCTB	
$V_{RRM}$	Peak repetitive reverse voltage	100		V
$V_{RWM}$	Working peak reverse voltage			
$V_R$	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage	70		V
$I_O$	Average rectified output current	30		A
$I_{FSM}$	Non-Repetitive peak forward surge current (8.3ms half sine wave)	250		A
$R_{\theta Jc}$	Thermal resistance from junction to case , $T_c=25^{\circ}C$	2.0	3.0	$^{\circ}C/W$
$R_{\theta JA}$	Thermal resistance from junction to ambient	62.5		$^{\circ}C/W$
$T_j$	Junction temperature	150		$^{\circ}C$
$T_{stg}$	Storage temperature	-55~+150		$^{\circ}C$

#### ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1mA$	100			V
Reverse current	$I_R$	$V_R=100V$	$T_j=25^{\circ}C$	30	100	$\mu A$
			$T_j=125^{\circ}C$	20		mA
Forward voltage	$V_F$	$I_F=10A$	$T_j=25^{\circ}C$	0.53		V
			$T_j=125^{\circ}C$	0.50		V
		$I_F=20A$	$T_j=25^{\circ}C$	0.67	0.72	V
			$T_j=125^{\circ}C$	0.64		V

\*Pulse test: pulse width  $\leq 300\mu s$ , duty cycles  $\leq 2.0\%$ .

FIG.1: FORWARD CURRENT DERATING CURVE

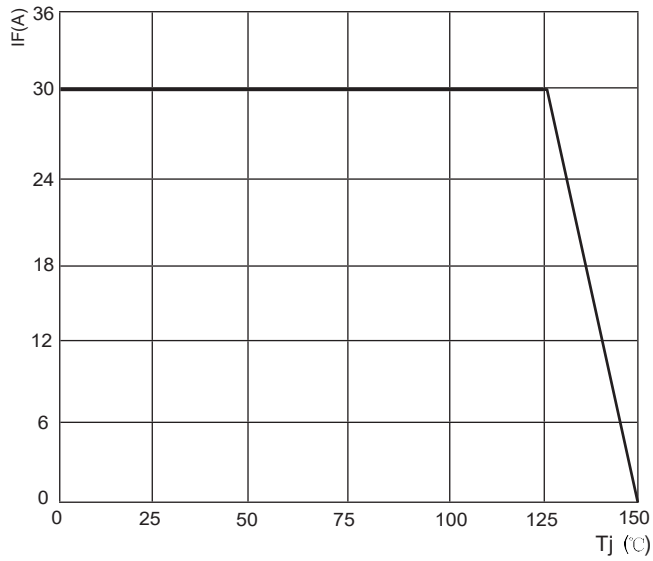


FIG.2: TYPICAL FORWARD CHARACTERISTICS

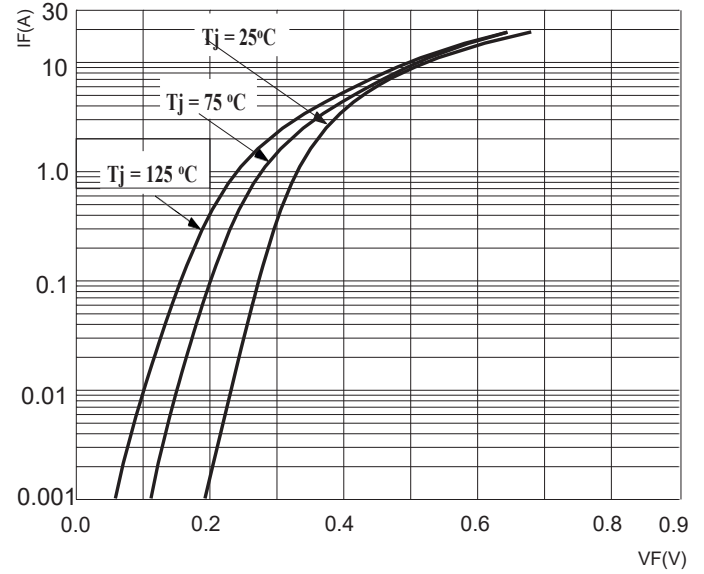


FIG.3: TOTAL CAPACITANCE DERATING CURVE

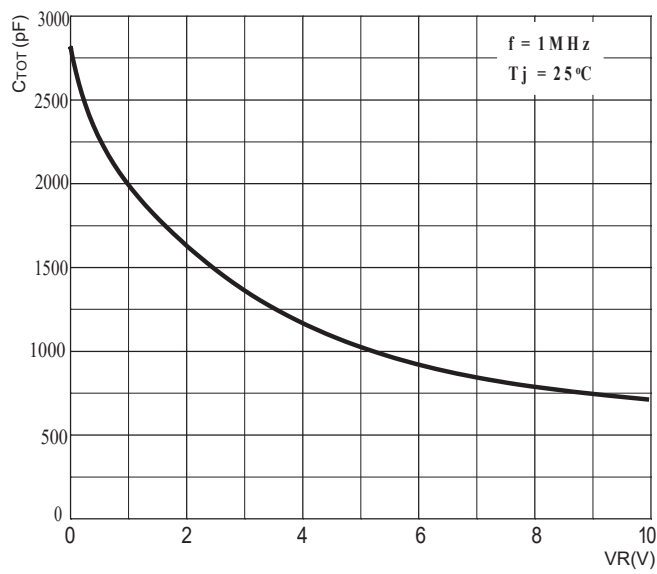


FIG.4: TYPICAL REVERSE CHARACTERISTICS

